

Microwave radiation induced magneto-oscillations in the longitudinal and transverse resistance of a two dimensional electron gas

S.A. Studenikin[#], M. Potemski[#], P.T. Coleridge, A. Sachrajda, and Z.R. Wasilewski

Institute for Microstructural Sciences, National Research Council of Canada, Ottawa, Ontario, K1A 0R6, Canada

[#] Grenoble High Magnetic Field Laboratory, MPI/FKF and CNRS, BP 166, 38042 Grenoble, Cedex 9, France

(Dated: 7 October 2003)

We confirm the existence of magneto-resistance oscillations in a microwave-irradiated two-dimensional electron gas, first reported in a series of papers by Zhudov et al.[1] and Maniet al.[2]. In our experiments, on a sample with a more moderate mobility, the microwave induced oscillations are observed not only in the longitudinal – but also in the transverse-resistance (Hall resistance). The phase of the oscillations is such that the decrease (increase) in the longitudinal resistance is accompanied by an increase (decrease) in the absolute value of the Hall resistance. We believe that these new results provide valuable new information to better understand the origin of this interesting phenomenon.

PACS numbers: 73.50.Jt, 73.40.-c, 78.67.-n, 78.20.Ls, 73.43.-f

A. Introduction

The new physics that results from subjecting a high mobility two-dimensional electron gas (2DEG) to magnetic fields continues to provide new and fascinating phenomena. Among them is the recently reported observation of oscillations in the longitudinal magneto-resistance (ρ_{xx}) of a 2DEG irradiated by microwaves with frequencies in the range 5 – 100 GHz [1]. These oscillations have been observed in samples with very high mobility, at moderately low temperatures $T \sim 1$ K, and at low magnetic fields (~ 1 T). The periodicity of these oscillations is determined by the ratio of $\omega_c = eB/m$, in contrast to the well established case of Shubnikov-de Haas (SdH) oscillations which they are determined by the ratio $E_F = \hbar \omega_c$. Here, as usual: $\omega_c = eB/m$ is the electron cyclotron energy, with m the electron effective mass and E_F denotes the Fermi energy. Under strong microwave irradiation and with samples that have a sufficiently high mobility, the minima in ρ_{xx} become transformed into "zero resistance states" [2].

It has been proposed [3, 4, 5] that these microwave induced resistance oscillations (MIROs) can be understood in terms of an additional, microwave-induced current which flows with or against the direction of the applied electric field, depending on whether $n - 1 = 2, 3, \dots$ or $n < 1 = \omega_c$. $n + 1 = 2$, with $n = 1, 2, 3, \dots$ integers. It has further been suggested that zero resistance states appear because of domain formation when the absolute conductivity becomes negative [6]. Alternatively, this effect may reflect even more elaborate physics [2]. A characteristic of the theoretical treatments is that no microwave induced changes to ρ_{xx} are expected for ω_c exactly equal to $1, 2, 3, \dots$ [3, 4, 5]. Conventional cyclotron resonance absorption, which involves direct excitations and conservation of the motion of the centre of the electron

cyclotron orbit, does not result in any additional current (i.e. does not change the conductivity). The additional current appears as a result of indirect (off-diagonal) electron excitations and involves other factors, such as impurities or phonons [3, 4, 5]. Therefore MIROs are not necessarily triggered by a resonant absorption process, but more likely result from non-resonant microwave-induced excitations of the 2DEG, with the modulation of ρ_{xx} being a consequence of periodically changing conditions for the additional current to flow preferentially with or against the applied electric field.

Diagrammatic calculations of the changes in the conductivity tensor induced by the microwave-excited disorder-scattered electrons reproduce the main experimental trends, in particular the observed period and the phase [4]. Nevertheless, other experimental features such as the exact shape of the oscillations as a function of magnetic field [7] and the temperature dependence of the MIROs amplitudes are not as well understood. Another puzzle is that while the theory [4] invokes an impurity-disorder mechanism to explain the MIROs, it is found experimentally that the oscillations become more clearly pronounced as the mobility is increased and the disorder is reduced.

In this paper we address another relevant issue, whether MIROs are a unique property of the longitudinal resistance (or alternatively ρ_{xx}) or whether they also appear in the transverse resistance ρ_{xy} . So far, MIROs have been reported exclusively in measurements of ρ_{xx} or ρ_{xx} [8]. It is sometimes argued that the absence of microwave induced features in ρ_{xy} implies that MIROs have a classical origin rather than being a many-body effect. Theoretically, it has been predicted that both ρ_{xx} and ρ_{xy} should be influenced by microwave irradiation and that the resistance changes ρ_{xx} and ρ_{xy} , at least under some approximations, should be comparable in magnitude [4]. Results are presented here that show, for the first time, that microwave induced changes, of a similar magnitude, can be observed in measurements of both ρ_{xx} and ρ_{xy} . It is shown that the observed oscillations in ρ_{xy}

sergei.studenikin@nrc.ca

cannot be attributed to more trivial effects, such as an admixture of ρ_{xy} and ρ_{xx} but rather must be associated with microwave induced oscillations in both the longitudinal conductivity ρ_{xx} and the transverse conductivity ρ_{xy} . Possible consequences of our experimental findings are discussed.

B. Experimental

The measurements have been performed at He^4 bath temperatures ($T = 1.4 - 4.2 \text{ K}$), on a GaAs/AlGaAs heterojunction (grown at NRC) that had a 2DEG mobility of $\mu = 4.0 \times 10^6 \text{ cm}^2/\text{Vs}$ and density of $n = 1.9 \times 10^{11} \text{ cm}^{-2}$ after a brief illumination using a red LED. The sample was cleaved into a rectangular shape to form a $8 \times 2 \text{ mm}^2$ Hall bar and contacted at the edges using small In dots. The length-to-width ratio between potential and Hall contacts was 1.3/2.

An Anritsu 69377B Signal Generator (operating at 0.01-50 GHz, with typical output power of a few mW) was used as the source of microwaves (MWs). They were delivered into the cryostat through a semirigid 0.085 inch coaxial cable which had a typical attenuation factor of 6-10 dB near 50 GHz. The cable was terminated with a small antenna used to irradiate the sample which was mounted a few millimeters away. A small cylindrical cavity of MW absorbing material was constructed around the sample to suppress any cavity modes produced by metallic components of the cryostat. The (perpendicular) magnetic fields produced by the superconducting magnet were carefully calibrated using NMR and Hall effect probes and were checked by measuring the EPR signal of DPPH powder mounted on a thermoresistor. Longitudinal and transverse resistances of the 2DEG were measured using standard AC techniques, (at 15 Hz and with measuring currents $\sim 1 \text{ A}$). The data presented is the difference, $\Delta\rho_{xx}$, between resistivities measured for two identical field sweeps with and without the application of MWs.

C. Results and discussion

Representative experimental traces of the longitudinal magnetoresistance under microwave radiation are shown in Fig. 1a for different powers, Fig. 1b for different frequencies, and Fig. 1c for different temperatures. The data in Fig. 1 is very similar that previously reported for other MROs [1, 2] (although the mobility of the sample used here was too low to achieve "zero resistance" states), and confirms again that phenomena is universal, independent of the source of the sample. Each $\Delta\rho_{xx}$ trace is plotted against the dimensionless parameter ω/ω_c , i.e., the ratio of microwave to cyclotron frequency, assuming the cyclotron mass, $m^* = 0.067 m_e$. In agreement with previous observations [1, 2], $\Delta\rho_{xx}$ is found to be an oscillatory function of the inverse magnetic field, with the fundamen-

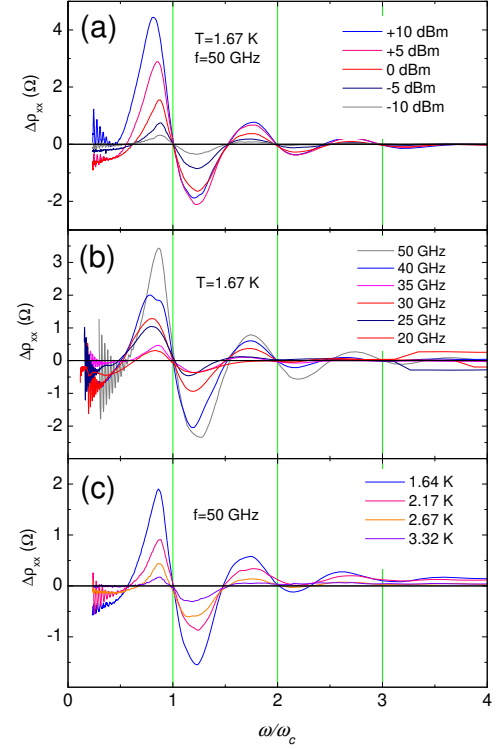


FIG. 1: Experimental traces of $\Delta\rho_{xx}$ induced by microwave radiation plotted against normalized inverse magnetic field ω/ω_c (ω and ω_c is the radiation and cyclotron cyclic frequency correspondingly) for different powers (a), different frequencies (b), and for different temperatures (c).

tal period $(1/B) = (1/B)(\omega/\omega_c)$. It is apparent from Fig. 1 that the oscillations are damped by increasing temperature and by decreasing magnetic field, microwave power or microwave frequency. The dependence of $\Delta\rho_{xx}$ on the magnetic field can be roughly described as

$$\Delta\rho_{xx} = A \exp(-D_M \omega/\omega_c) \sin(2\omega/\omega_c) \quad (1)$$

with a phase corresponding to a positive coefficient A . The damping parameter D_M is relatively insensitive to microwave power or frequency. We find that $D_M = 0.3 \text{ m eV}$ at $T = 1.64 \text{ K}$ and increases somewhat at higher temperatures. While Eq.(1) provides a good description of the higher order oscillations there are deviations around the fundamental cyclotron resonance ($n=1$); the exact positions of the maxima and minima in $\Delta\rho_{xx}$ become sensitive to the experimental parameters such as microwave power and temperature. This may be associated with the effect of the cyclotron resonance which can produce significant changes in the dielectric function of the 2DEG. The most robust and well defined feature of the MROs are the positions of the zeros in $\Delta\rho_{xx}$ that occur when $\omega/\omega_c = 1/2; 3/2; 5/2; \dots$. This is in agreement with theoretical predictions [3, 4, 5].

The standard expression for the amplitude of the SdH

oscillations is [11]:

$$\rho_{xx} = 4 \rho_0 D_{th} (X_T) \exp(-\frac{1}{2} \frac{1}{c} \frac{1}{q}) \quad (2)$$

where the thermal damping factor, D_{th} , is given by $X_T = \sinh(X_T)$ with $X_T = 2 \sqrt{2} kT / \hbar c$ and where q is the quantum lifetime.

If the SdH oscillations in ρ_{xx} (see for example figure 2) are analysed using this expression the damping is dominated by D_{th} and no oscillations are visible in the low field region when the M IROs appear. However, measurements at lower temperatures (below 100m K) in another sample cut from the same wafer, show SdH oscillations to below .05 T which can be used to extract a value for q of approximately 10ps. This corresponds to a damping coefficient $\sim \frac{1}{c} \frac{1}{q}$ of 0.27 meV, essentially identical to the coefficient D_M obtained above for the M IROs.

At 0.1 tesla, $q = 10$ ps corresponds to a (Gaussian) Landau level broadening parameter of order 0.04 meV compared with the cyclotron spacing of 0.17 meV [9]. Therefore, despite the fact that thermal blurring of the distribution function suppresses the observation of the SdH oscillations at higher temperatures a well-defined Landau level structure still exists in the density of states. Furthermore, the damping of the M IROs appears to be the same as the disorder broadening of the Landau levels. This explains why M IROs can only be observed in very high mobility 2DEG samples where a well-defined Landau level structure persists in the very low fields corresponding to $\frac{1}{c} \frac{1}{q} \approx 1$.

For conventional SdH oscillations convolution of the Fermi function with the density of states produces a strong thermal degradation of the oscillations but this appears not to be the case for M IRO's. One explanation for this might be that the normal role of the Fermi function in producing a thermal smearing is masked by a stronger perturbation of the distribution function induced by the microwave radiation. It is only at higher temperatures (above about 1.5K) that the Fermi function can cause additional thermal smearing and give rise to a temperature dependent D_M .

In the following section we show that M IROs are not only evident in the longitudinal resistance but can be also observed in the Hall (transverse) resistance ρ_{xy} . This can be seen in Fig. 2, which illustrates the result of simultaneous measurements of ρ_{xx} and ρ_{xy} (right scale) and the MW induced deviations $\Delta\rho_{xx}$ and $\Delta\rho_{xy}$ (left axis). Despite the noise in the ρ_{xy} trace it is clear that microwave affects both resistances, and that the amplitudes of the two sets of oscillations are very similar. The noise is relatively large because the high mobility of the sample means $\rho_{xy} = \frac{1}{2} \rho_{xx}$ is of order 100 times smaller than $\rho_{xx} = \rho_{xx}$ when M IROs are observed so the inevitable errors associated with taking differences between large numbers become much more important for ρ_{xy} .

Note that ρ_{xy} , like ρ_{xx} , changes sign in reversed magnetic fields. This means the observation of M IROs in ρ_{xy} cannot be attributed to a trivial admixture of ρ_{xx} into the ρ_{xy} signal, due for example to misaligned contacts.

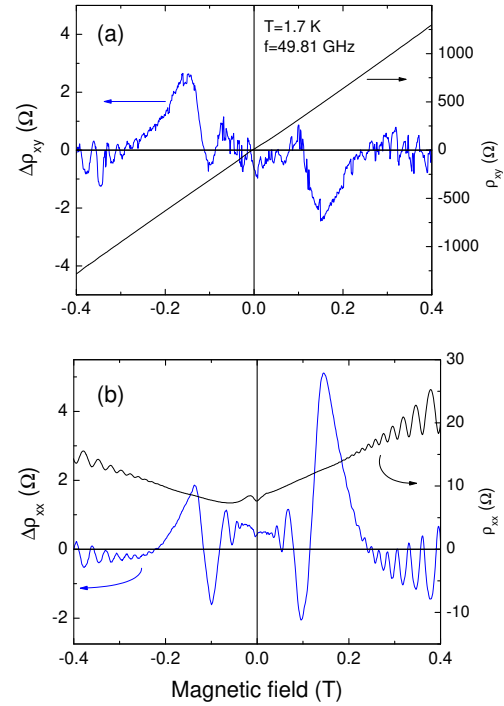


FIG. 2: Magnetic field dependencies of (a) the transverse magnetoresistivity ρ_{xy} and (b) the longitudinal magnetoresistivity ρ_{xx} and their deviations from dark values induced by microwave radiation $f = 49.8$ GHz at $T = 1.7$ K.

The absolute sign of ρ_{xy} depends on a sign convention but the fact that the sign of $\rho_{xy} = \frac{1}{2} \rho_{xx}$ is the opposite to the sign of ρ_{xx} is an unambiguous experimental observation that can be tested against theory.

Simple quantitative arguments can also be made to confirm that ρ_{xx} and ρ_{xy} do not just reflect changes in ρ_{xx} exclusively. If the standard expressions are used for inverting the conductivities (viz. $\rho_{xx} = \frac{1}{\sigma_{xx}} = \frac{1}{\sigma_{xx} + \sigma_{xy}^2 / \sigma_{xx}}$ and $\rho_{xy} = \frac{\sigma_{xy}}{\sigma_{xx} + \sigma_{xy}^2 / \sigma_{xx}}$) then it is straightforward to show that a small change in ρ_{xx} will produce changes in ρ_{xx} and ρ_{xy} related by $\rho_{xy} = \frac{2K}{1 + K^2} \rho_{xx}$ where $K = \frac{\sigma_{xy}}{\sigma_{xx}} = \frac{\rho_{xx}}{\rho_{xy}}$. While this gives the correct (observed) phase relationship between the two terms K is typically 0.02 so under the actual experimental conditions ρ_{xy} is predicted 20 times smaller than ρ_{xx} , in sharp contrast to the experimental results which show the ratio is actually about 2. An equivalent calculation shows, likewise, that the observed oscillations in ρ_{xx} and ρ_{xy} cannot result from changes in ρ_{xy} alone. We therefore conclude that both ρ_{xx} and ρ_{xy} are independently influenced by microwaves. The results in Fig.2 showing ρ_{xx} and ρ_{xy} oscillating in anti-phase correspond, for example, to an increase (decrease) in effective electron concentration when the longitudinal conductivity, ρ_{xx} , increases (decreases). A theoretical determination of the phase relationship between ρ_{xx} and ρ_{xy} has not yet been addressed directly [4].

D . Conclusions

In conclusion, we have confirmed the observation of microwave induced magneto-oscillations (MROs) in the longitudinal resistance of a 2DEG with a periodicity defined by the ratio of microwave to cyclotron frequencies [1, 2].

Our results indicate that a necessary condition for the observation of these oscillations is a pronounced modulation of the electronic density of states (Landau levels), in general agreement with predictions of existing theoretical models [3, 4, 5].

The temperature dependent damping of MROs is very different from the thermal damping of the Shubnikov-de Haas oscillations. It is not clear whether this is related to a temperature dependence of the Landau level broadening or some other mechanism. Experiments to address this issue are in progress.

If MROs are due to the scattering by impurities of microwave-excited electrons but at the same time require a pronounced modulation in the density of states, a subtle criteria would exist for optimum sample quality. It

would be interesting to check this if even higher mobility samples become available. However, phonon-assisted processes may also play a role [7] and effects resulting from the interplay between one-particle and collective excitations in the 2DEG [10] should also not be neglected. More experiments, and in particular complementary microwave absorption measurements, are needed to achieve a better understanding of this fascinating phenomena.

The major new result reported here is that MROs are not only present in the longitudinal resistance but can also be observed in the transverse component of the magneto-resistance. This is a non-trivial effect and requires that ρ_{xx} and ρ_{xy} both oscillate independently. The relative phase of the ρ_{xx} and ρ_{xy} oscillations experiment remains to be compared to theoretical predictions.

E . Acknowledgements

S.A.S. and A.S. acknowledge support of The Canadian Institute for Advanced Research (CIAR).

-
- [1] M.A. Zudov, R.R. Du, J.A. Simmons, and J.L. Reno, Phys. Rev. B 64, 201311 (2001); R.G. Mani, J.H. Smet, K. von Klitzing, V. Narayanamurti, W.B. Johnson, and V. Umansky, Proceedings of the 26th International Conference on the Physics of Semiconductors, (July 29th – August 2nd, 2003, Edinburgh, U.K.), edited by A.C. Long and J.H. Davies, (Institute of Physics), to be published; cond-mat/0305507.
 - [2] R.G. Mani, J.H. Smet, K. von Klitzing, V. Narayanamurti, W.B. Johnson, and V. Umansky, Nature (London) 420, 646 (2002); M.A. Zudov, R.R. Du, J.A. Simmons, and J.L. Reno, Phys. Rev. B Phys. Rev. Lett. 90, 46807 (2003).
 - [3] V.I. Ryzhii, Fiz. Tverd. Tela 11, 2577 (1969) [Sov. Phys. Solid State 11, 2078 (1970)]; V.I. Ryzhii et al., Fiz. Tekh. Poluprovodn. 20, 2078 (1986) [Sov. Phys. Semicond. 20, 1299 (1986)].
 - [4] A.C. Durst, S. Sachdev, N. Read, and S.M. Girvin, Phys. Rev. Lett. 91, 86803 (2003).
 - [5] J. Shi and X.C. Xie, Phys. Rev. Lett. 91, 86805 (2003).
 - [6] A.V. Andreev, I.L. Aleiner, and A.J. Millis, Phys. Rev. Lett. 91, 56803, (2003).
 - [7] For a recent review see special session at the EP 2D S-Nara 2003 conference proceedings to be published.
 - [8] Combinom easurement?
 - [9] The Gaussian level broadening, determined according to the self-consistent Born approximation, increases as $B^{1/2}$.
 - [10] D. Richards, Phys. Rev. B 61, 7517 (2000); B. Jusserand, M. ElKordi, and A. Cavanna, Phys. Rev. B 67, 233307 (2003).
 - [11] P.T. Coleridge, Phys. Rev. B 44, 3793 (1991).